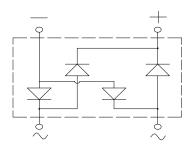


Fast Recovery Bridge Rectifiers





Features

- UL recognition, file #E313149
- Glass passivated chip junction
- Ideal for automated placement
- High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

Typical Applications

General purpose use in high frequency AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

Mechanical Data

• Package: YBS

Molding compound meets UL 94 V-0 flammability rating, -compliant, Halogen free

• **Terminals**: Tin plated leads, solderable per

J-STD-002 and JESD22-B102
• Polarity: As marked on body

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	RYBS3010
Device marking code			RYBS3010
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	V	1000
Maximum RMS Voltage	V_{RMS}	V	700
Maximum DC blocking Voltage	V _{DC}	V	1000
Average rectified output current @60Hz sine wave, R-load, Tc=110°C	Io	А	3.0
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25°C		А	90
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25℃	I _{FSM}		180
Current squared time @1ms≤t<8.3ms Tj=25°C,Rating of per diode	l²t	A ² s	33.6
Storage temperature	T_{stg}	°C	-55 ~ +150
Junction temperature	Tj	°C	-55 ~ + 150



■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	RYBS3010
Maximum reverse recovery time	t _{rr}	ns	I _F =0.5A,I _R =1.0A, I _{rr} =0.25A	500
Maximum instantaneous forward voltage drop per diode	V _F	V	I _{FM} =1.5A	1.3
Maximum DC reverse current at			Tj =25°C	5
rated DC blocking voltage per diode	IR IR	μΑ	Tj =125°C	100
Typical junction capacitance	Cj	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	

■Thermal Characteristics $(T_a=25 \degree C \text{ Unless otherwise specified})$

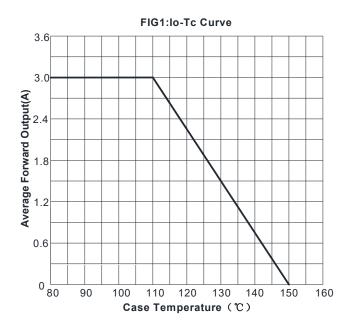
PARAMETER		SYMBOL	UNIT	RYBS3010
	Between Junction and Ambient	R _{0J-A}		55.0
Typical Thermal Resistance	Between Junction and Lead	$R_{\theta J\text{-}L}$	°C/W	15.0
rtoolotarioo	Between Junction and Case	R _{eJ-C}		10.0

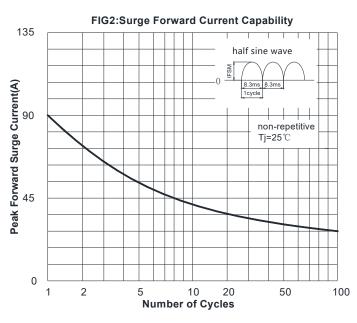
Note: Device mounted on P.C.B with 35mm*25mm*1.7mm.

■Ordering Information (Example)

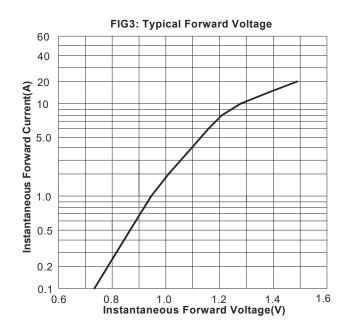
PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
RYBS3010	F1	Approximate 0.220	3000	1	42000	13" reel

■ Characteristics(Typical)









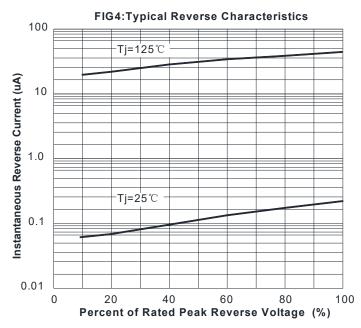
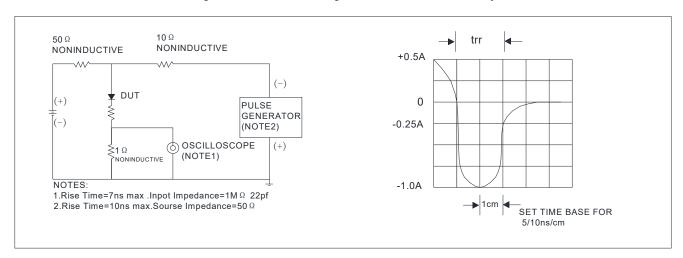
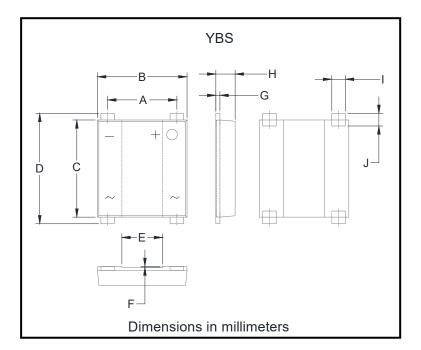


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time



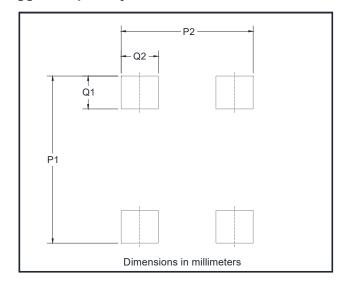


■ Outline Dimensions



YBS				
Dim	Min	Max		
Α	5.00	5.20		
В	6.50	6.70		
С	7.20	7.40		
D	7.90	8.60		
Е	2.90	3.10		
F	0.04	0.08		
G	0.27	0.40		
Н	1.30	1.50		
I	0.95	1.15		
J	0.70	1.05		

■ Suggested pad layout



Dim	Min	
P1	9.15	
P2	7.10	
Q1	1.80	
Ω2	2.00	



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